

Interface driver for microcomputer peripheral and display devices

BA13002F

The BA13002F is a high current transistor array consisting of six circuits of Darlington transistors. Because it incorporates built-in surge-absorbing diodes and base current-control resistors needed when using inductive loads such as relay coils, attachments can be kept to a minimum.

With an output withstand voltage as high as 20V and an output current (sink current) of 320mA, this product is ideal for use with various drivers and as an interface with other elements.

● Applications

Drivers for LEDs, lamps, relays and solenoids

Interface with other elements

● Features

- 1) Output withstand voltage (V_{CEO}) of 20V.
- 2) High output current (I_O) of 320mA (max.).
- 3) High current amplification factor (h_{FE}) of 1000 (min.).
- 4) Wide range of voltages (-25 to 20V) can be applied to input.
- 5) Equipped with output surge-absorbing clamp diode.
- 6) Equipped with strobe input pin.

● Absolute maximum ratings ($T_a=20^\circ\text{C}$ to $+75^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Power supply voltage	V_{CC}	10	V
Output withstand voltage	V_{CEO}	-0.5~20	V
Output current	I_O	320	mA
Input voltage	V_I	-25~20	V
Strobe input voltage	$V_{I(STB)}$	20	V
Clamp diode reverse voltage	$V_R(D)$	20	V
Clamp diode forward current	$I_F(D)$	320	mA
Power dissipation ($T_a=25^\circ\text{C}$)	P_d	500 *1	mW
Operating temperature	T_{OPR}	-20~75	°C
Storage temperature	T_{STG}	-55~125	°C

*1 Reduced by 5.0mW for each increase in T_a of 1°C over 25°C .

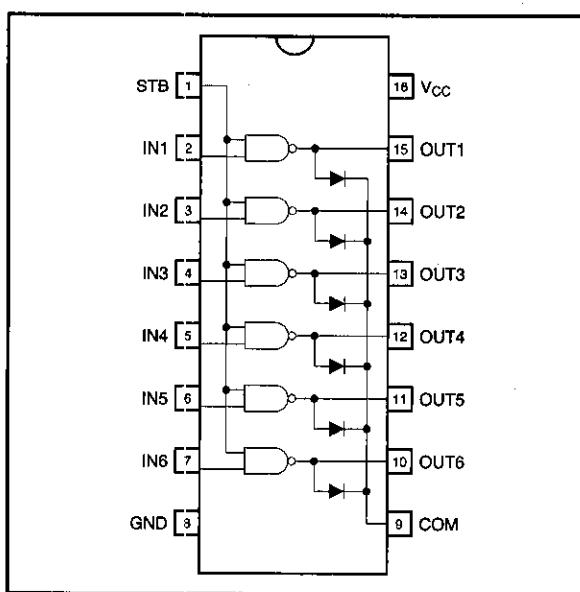
(when a 50 x 50 x 1.6 mm glass epoxy PCB is used).

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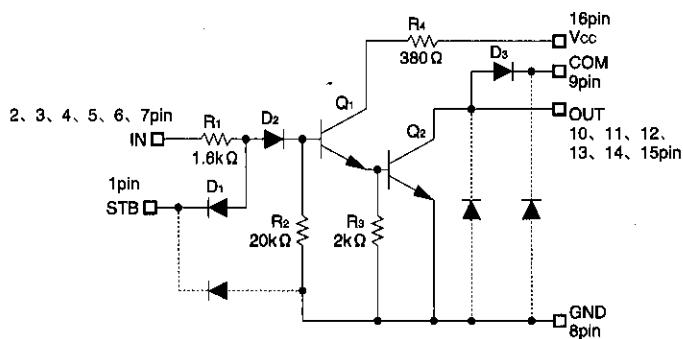
● Block diagram

● Recommended operating conditions ($T_a = -20^\circ\text{C}$ to 75°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Power supply voltage	V _{CC}	3	—	8	V	
Output voltage	V _O	0	—	20	V	
Output current	I _O	0	—	300	mA	Duty cycle of 20 % or less: V _{CC} =6.5 V
		0	—	150	mA	Duty cycle of 40 % or less: V _{CC} =6.5 V
"H" input voltage (strobe)	V _{IH(STB)}	2.4	—	18	V	
"L" input voltage (strobe)	V _{IL(STB)}	0	—	0.2	V	
"H" input voltage	V _{IH}	3.2	—	18	V	I _O =300mA
"L" input voltage	V _{IL}	0	—	0.7	V	I _{O (leak)} =50 μA

● Internal circuit configuration diagram

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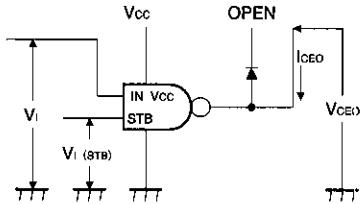
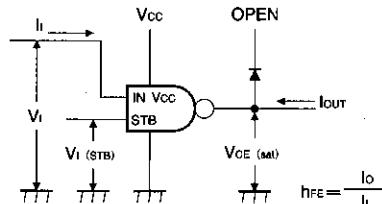
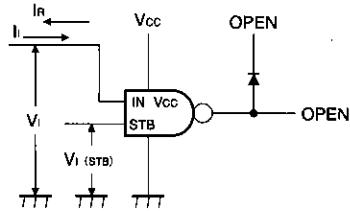
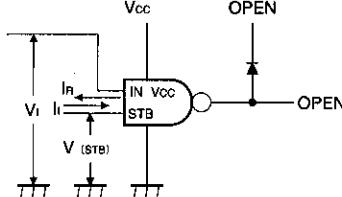
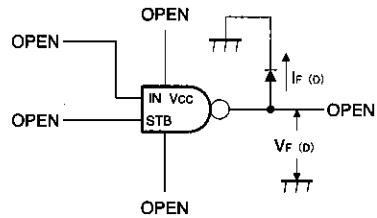
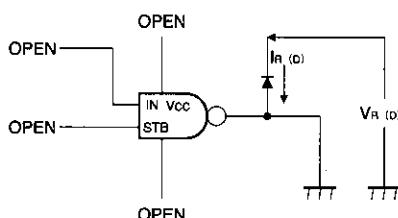
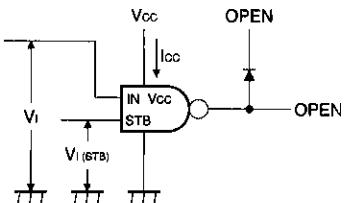


(Resistor values are typical values.)

● Electrical characteristics (unless otherwise noted, Ta = -25°C to +75°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions	Measurement Circuit
Output withstand voltage	V _{CEO}	20	—	—	V	V _{CC} =8V, V _I =18V, V _{I(STB)} =0.2V, I _{CEO} =100 μA	Fig.1
Output saturation voltage	V _{CE(sat)}	—	0.6	1.0	V	V _I =7V V _{I(STB)} =2.4V	Fig.2
		—	0.5	0.85	V		
		—	0.3	0.5	V		
Clamp diode forward voltage	V _{F(D)}	—	1.4	2.4	V	I _{F(D)} =320mA	Fig.5
Clamp diode reverse voltage	V _{R(D)}	20	40	—	V	I _{R(D)} =100 μA	Fig.6
Power supply current	I _{CC}	—	120	200	mA	V _{CC} =8V, V _I =7V(all inputs), V _{I(STB)} =2.4V	Fig.7
DC current amplification factor	h _{FE}	1000	3000	—		V _{CE} =4V, V _{CC} =6.5V, I _O =300mA, Ta=25°C	Fig.2
Turn-on time	t _{ON}	—	0.1	—	μS	Refer to test circuit diagrams.	Fig.8
Turn-off time	t _{OFF}	—	0.1	—			
Input current	I _I	—	0.5	1.4	mA	V _{CC} =8V, V _I =3.2V, V _{I(STB)} =2.4V	Fig.3
Input reverse current	I _{IR}	—	—	-20	μA	V _{CC} =8V, V _I =-25V	
Strobe input current	I _{I(STB)}	—	-7.9	—	mA	V _{CC} =8V, V _I =3.2V(all inputs), V _{I(STB)} =0.2V	Fig.4
Strobe input reverse current	I _{IR(STB)}	—	—	20	μA	V _{CC} =8V, V _I =0V, V _{I(STB)} =20V	

● Measurement circuits

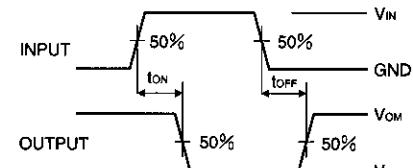
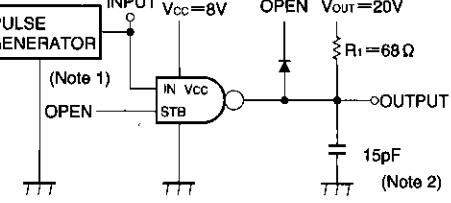
Fig.1 Output withstand voltage V_{CEO} Fig.2 Output saturation voltage $V_{CE(\text{sat})}$
DC current amplification factor h_{FE} Fig.3 Input current I_i • Input reverse current I_r Fig.4 Strobe input current $I_{(tsb)}$ •
Strobe input reverse current $I_{(tsb)}$ Fig.5 Clamp diode forward voltage $V_{F(D)}$ Fig.6 Clamp diode reverse voltage $V_{R(D)}$ Fig.7 Power supply current I_{CC}

● Circuit operation

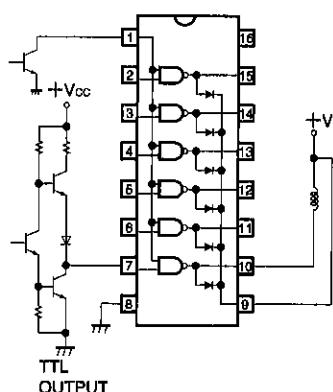
Input/output logic table

IN	STB	OUT
L	L	H
H	L	H
L	H	H
H	H	L

The driver operates based on the logic in the above table.

Fig.8 Turn-on time t_{ON}
Turn-off time t_{OFF} (Note 1) Pulse width: 10 μs, duty cycle ≤ 5 %
(Note 2) Including probe capacitance

● Application example



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● Operation notes

Make sure that the duty cycle – output current characteristic range is not exceeded.

● Thermal reduction curve

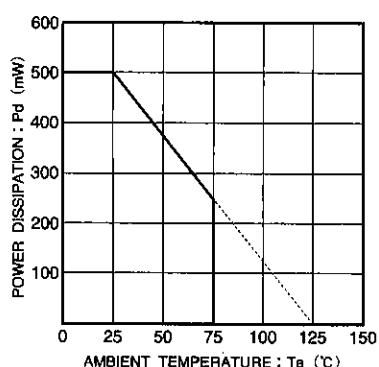


Fig.9 Thermal reduction curve

● Measurement data

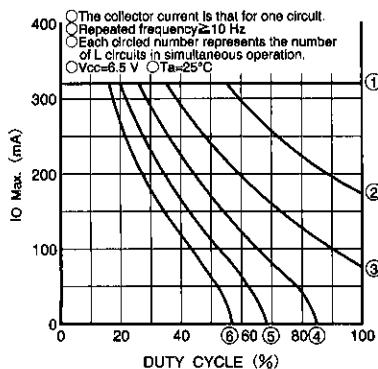


Fig.10 Duty cycle - collector current characteristics (I)

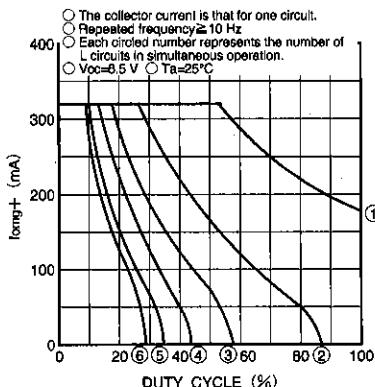


Fig.11 Duty cycle - collector current characteristics (II)

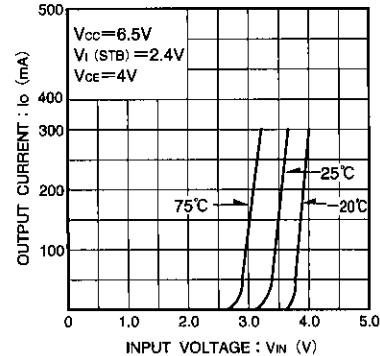


Fig.12 Output current - input voltage characteristics

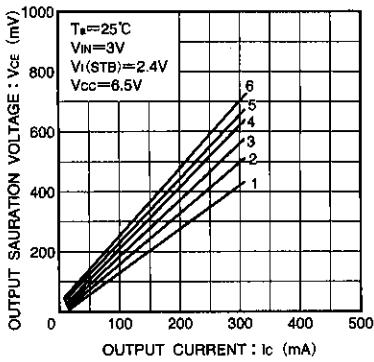


Fig.13 Output saturation voltage - output current characteristics

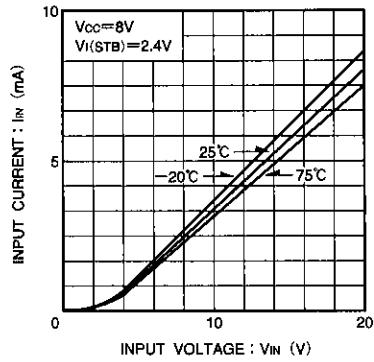


Fig.14 Input current - input voltage characteristics

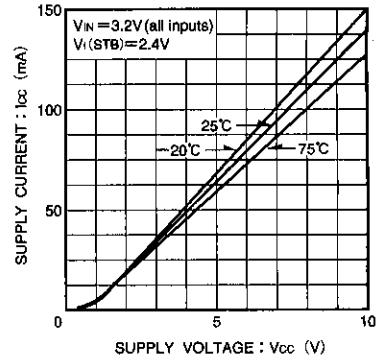


Fig.15 Power supply current - power supply voltage characteristics

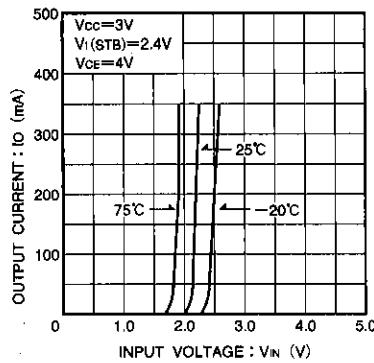


Fig.16 Output current - input voltage characteristics 1

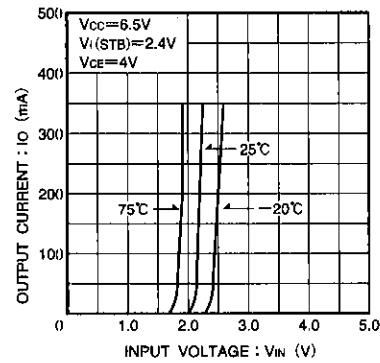


Fig.17 Output current - input voltage characteristics

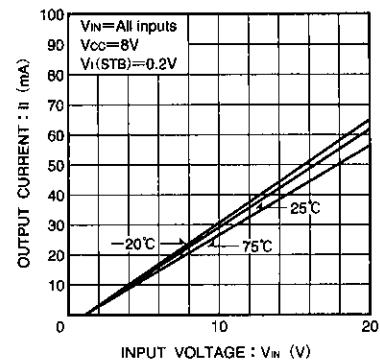
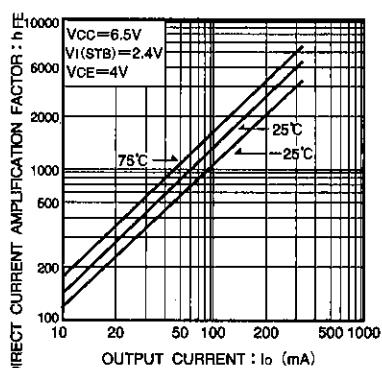
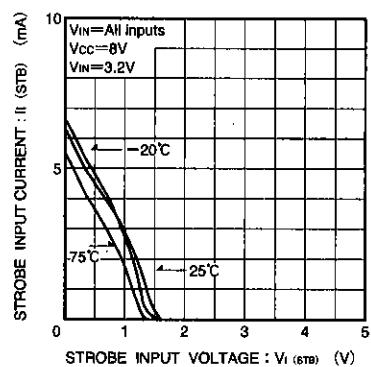
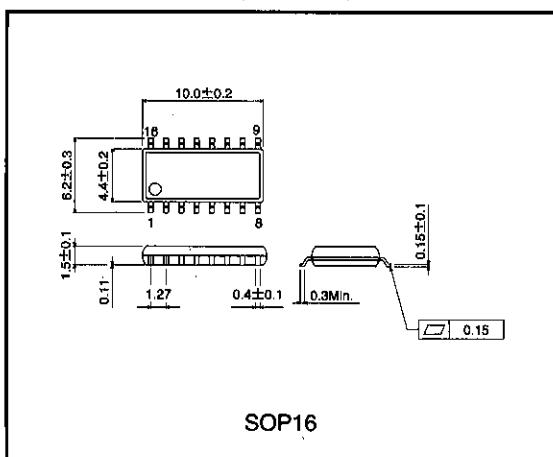


Fig.18 Input current - input voltage characteristics

● Measurement data



● External dimensions (Units: mm)



Transistor arrays

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